Supplementary Information

All Annealing-Free Solution-Processed Highly Flexible Organic Solar

Cells

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Fig. S1 $R_{sq}/R_{sq(o)}$ of the PEDOT:PSS anodes treated by CF₃SO₃H as a function of storage days in air atmosphere.



Fig. S2 Raman spectra of the as-cast air-dried PEDOT:PSS films and the room-temperature CF₃SO₃H-doped and air-dried PEDOT:PSS anodes.



Fig. S3 Weights of the devices including the rigid ones on glass substrates (**a**), the flexible ones on 200- μ m-thick PET substrates (**b**) and the ultrathin soft ones on 24- μ m-thick PE substrates (**c**).



Fig. S4 Plotted values of PCEs of the rigid and flexible OSCs with annealing-free functional layers reported recently.



Sample	R	d/2	3
PE: 24 μm <i>, r</i> : 0.25 mm	262 μm	12 μm	4.58%
PET: 200 μm <i>, r</i> : 0.25 mm	350 μm	100 μm	28.57%
PE: 24 μm <i>, r</i> : 0.50 mm	512 μm	12 μm	2.34%
PET: 200 μm <i>, r</i> : 0.50 mm	600 μm	100 μm	16.67%

Fig. S5 Schematic illustration of the cross-sectional dimensions. Here, ε is the normal strain on the vertical cross-sectional plane, R is the radius of curvature, and d is the thickness of the PE and PET substrates, respectively.



Fig. S6 Cracks of the PM6:Y6 active blends (see bottom regions) coated on the 200- μ m-thick rigid PET substrates in a harsh flexing at *r* of 0.25 mm.



Fig. S7 Cracks of Al top electrodes on 50- μ m-thick PET substrates and the 50- μ m-thick PET substrates in 100 cyclic flexing tests. (**a**,**b**) Al top electrodes with flexing at *r* of 0.50 and 0.25 mm, respectively. (**c**,**d**) The PET in the flexing at *r* of 0.50 mm and 0.25 mm, respectively. Scale bar: 50 μ m.



Fig. S8 (**a**,**b**) Pristine annealing-free solution-processed highly flexible organic solar cells. (**b**,**c**) Waved configuration and wrinkled configuration of the flexible devices through placing them on a pre-strained PDMS stamp (thickness: ca. 1 μ m). (**d**) Due to the soft property, the device foils were hung on the metallic needles (radius: 0.25 mm). (**e**) The highly flexible device attached to PDMS elastomeric supports under three-dimensional deformation by pressure from a 0.2 mm-diameter metallic object. (**f**) The highly flexible devices attached to the sleeves of the shirt for a potential wearable integration in the future.

Device	TE	AL	Annealing-free	V _{oc} (V)	J _{sc} (mA	FF (%)	PCE (%)	Ref.
			components		cm⁻²)		(Ave.)	
Rigid	ITO/	PM6:C4	AL,TME	0.689	15.74	67.01	7.28	[S1]
OSCs	Glass						(6.96)	
		PM6:C6	AL,TME	0.84	23.82	72.68	14.54 (14.37)	[\$1]
		PBDS-T: ITIC	AL,TME	0.985	18.68	60.01	11.06	[S2]
		PBDB-T:IDTCN-C	AL,TME	0.84	20.33	69.6	11.92 (11.75)	[\$3]
		PBDB-T:IDTCN-O	AL,TME	0.91	19.96	73.2	13.28 (12.91)	
		PBDB-T:IDTCN-S	AL,TME	0.85	19.04	65.7	10.60 (10.34)	
		DTBDT-Rho: PC ₇₁ BM	AL,TME	0.81	17.2	51.0	7.10	[\$4]
		PTB7-TH: PC ₇₁ BM	AL,TME	0.080	18.74	71.27	10.53	[\$5]

Tab. S1 Summaries of photovoltaic characteristics of the annealing-free OSCs

Flexible OSCs		PM6:Y6	AL,TME	0.86	24.3	73.2	15.2	[S6]
		PffBT-2TPF4-9/1:	AL,TME	0.769	17.18	70.8	9.4	[\$7]
		РСВМ					(9.1)	
	PEDOT:PSS/	PM6:Y6	TE, HTL, AL,	0.840	24.55	73.1	15.08	Here
	Glass		ETL,TME					
	Ag NW/	PTB7-Th:	ETL, AL,TME	0.79	18.51	68.68	10.04	[S8]
	PET	PC ₇₁ BM						
	Ag NW/	PTB7-Th:	AL,TME	0.764	17.4	64.2	8.75	[S9]
	PET	PC ₇₁ BM					(8.56)	
	PEDOT:PSS/	PM6:Y6	TE, HTL, AL,	0.84	23.92	0.729	14.66	Here
	PE		ETL,TME					

TE: transparent electrode; AL: active layer; HTL: hole-transport layer; ETL: electron-transport layer; TME: top metal electrode.

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